

## **INCHANGE SEMICONDUCTOR**

# **Isc N-Channel MOSFET Transistor**

## IPA60R600P6

### • FEATURES

- With TO-220F Package
- Drain Source Voltage-
- : V<sub>DSS</sub>=600V(Min)
- Static Drain-Source On-Resistance : R<sub>DS(on)</sub> = 0.6 Ω (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## APPLICATIONS

Switching applications

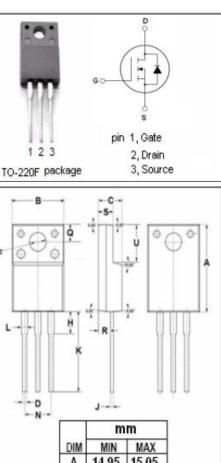
### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	600	V
V <sub>GSS</sub>	Gate-Source Voltage	±20	V
ID	Drain Current-Continuous @Tc=25℃   (V <sub>GS</sub> at 10V)   Tc=100℃	7.3 4.6	А
I <sub>DM</sub>	Drain Current-Single Pulsed	18	А
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25°C	28	W
Tj	Max. Operating Junction Temperature	-55~150	°C
T <sub>stg</sub>	Storage Temperature	-55~150	°C

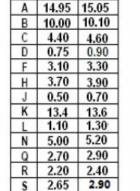
#### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	4.5	°C/W
Rth(ch-a)	Channel-to-ambient thermal resistance	80	°C/W

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F



6.40

6.60

U





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### • ELECTRICAL CHARACTERISTICS

 $T_{\text{C}}\text{=}25^\circ\!\!\mathbb{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =1mA	600			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS}$ = $V_{GS}$ ; I <sub>D</sub> =0.2mA	3.5	4	4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =2.4A		0.54	0.6	Ω
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0V			±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 600V; V <sub>GS</sub> = 0V;Tj=25°C V <sub>DS</sub> = 600V; V <sub>GS</sub> = 0V; Tj=150°C		10	1	μA
V <sub>SDF</sub>	Diode forward voltage	$I_{SD}$ =3A, $V_{GS}$ = 0 V		0.9		v

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